Title: Predicting New Graphene - Boron Nitride 2D Nano-Materials: Structure Electron Bands Optical Response and Vibrations

Date: May 07, 2014 12:25 PM

URL: http://pirsa.org/14050048

Abstract: <span>The goal of this research is to investigate theoretically the possibility of creating graphene-based semiconducting 2D heterosystems that allow tailoring of the band gap and creating states inside the gap by demand. Such systems are created in our computational experiment by depositing graphene on a layer of hexagonal boron nitride and adding hydrogen on top and bottom of the systems to passivate the dangling bonds and create covalent bonding between the layers of the system of interest. Apart from the atomic structure the thermal stability of the heterosystems their optical and vibrational properties were also studied. In this research four dierent bilayers and their properties are presented.

## oal of this Research

## What

The goal of this research is to analyze theoretically how to create graphene and BN based **semiconducting** 2D heterosystems and to offer a tool for tailoring the band gap and/or creating states nside the gap by demand.

### How

buch systems are created in our computational experiment by 'numerically" depositing graphene on a hexagonal boron nitride monolayer and adding hydrogen on top and bottom of the systems to passivate the dangling bonds and form covalent bonding petween the layers. At the same time, the intralayer covalent bonding opens the band gap of the bilayer, thus making the material semiconducting.

### Properties.

Apart from the atomic structure and DOS, the thermal stability of the heterosystems, their optical and vibrational properties were also studied using ab-initio molecular dynamics tools. 2D Electron Band Engineering: Application of High Performance Computing to Quantum Nano-Systems

Activation and Goal of his Research

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Specific Structures an Their Density of State Thermal Stability and

## raphene

### /hat is this revolutionary laterial?

s discovery was awarded the D10 Nobel Prize in Physics [K. Novoselov, A. K. Geim, S. V. orozov, et. al. Science **306**, D6 (2004)]. Graphene is a *sp*<sup>2</sup> onded 2D sheet of carbon in a anse honeycomb crystal lattice. his leads to an extremely strong aterial with record high ectron mobility due to linear and dispersion. However, it also as a zero band gap, making it a emi-metal.

2D Electron Band

Motivation and Goal of his Research

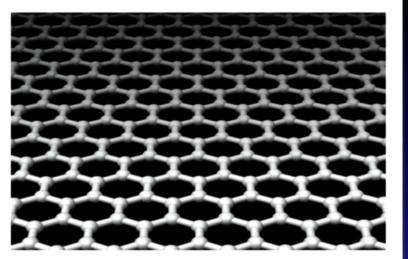
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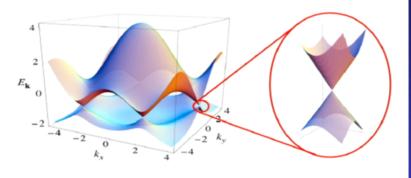
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2D Electron Band Engineering: Application of High Performance Computing to Quantum Nano-Systems

Wilk

Motivation and Goal of this Research

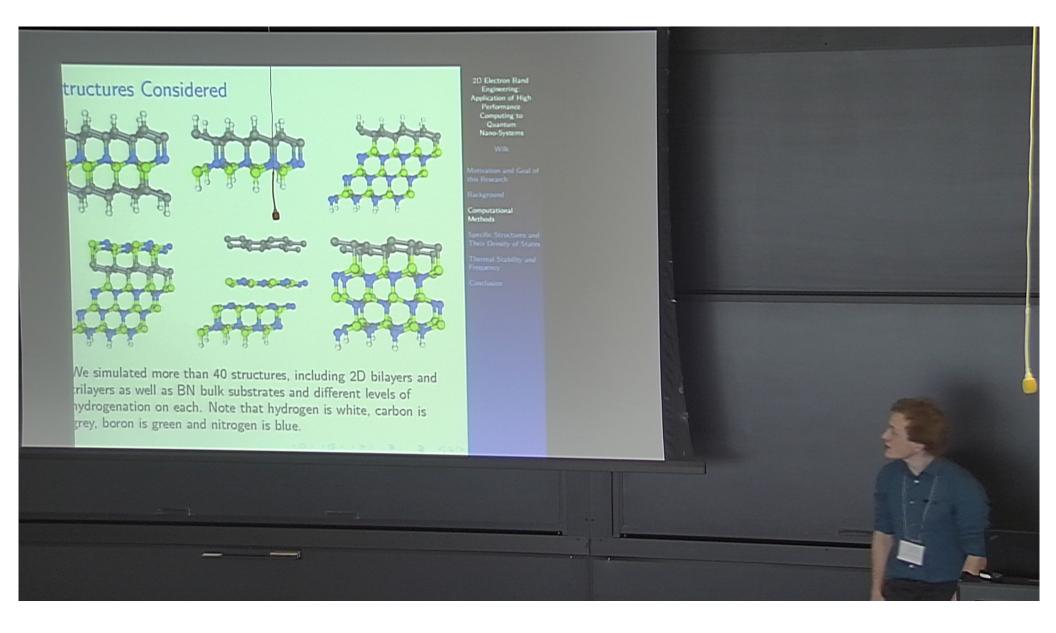
#### Background

Computational Methods

Specific Structures and Their Density of States

Thermal Stability and Frequency

Conclusion



# hifted Hydrogenated Bilayer (AB Stacking)

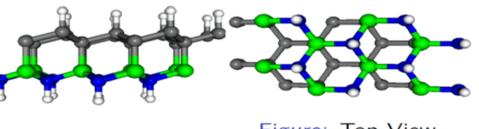


Figure: Side View

Figure: Top View

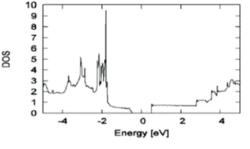


Figure: DOS

# The AB stacked hydrogenated bilayer

The so-called AB-stacked hydrogenated bilayer is shifted in the k-direction by a quarter of the length and in the y-direction by a half of the width from the AA stacked version, in which atoms are ocated on top of each other. This follows the stacking sequence of the cubic structure. The change in structure from AA to AB sequence lowered the energy by 0.038 eV per unit cell of 6 atoms. Due to the similarity of the structures, the difference in band gaps s 0.1 eV, with 1.0 eV for the AB-stacked bilayer.

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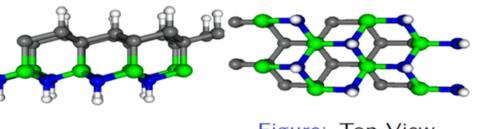


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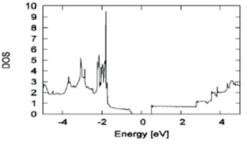


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